

#### **Description**

The 74LVCE1G32 is a single 2-input positive OR gate with a standard totem pole output. The device is designed for operation with a power supply range of 1.4V to 5.5V. The inputs are tolerant to 5.5V allowing this device to be used in a mixed voltage environment. The device is fully specified for partial power down applications using  $I_{\rm OFF}$ . The  $I_{\rm OFF}$  circuitry disables the output preventing damaging current backflow when the device is powered down.

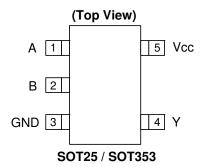
The gate performs the positive Boolean function:

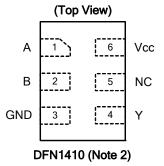
$$Y=A+B \text{ or } Y=\overline{\overline{A}\bullet \overline{B}}$$

#### **Features**

- Extended Supply Voltage Range from 1.4 to 5.5V
- Switching speed characterized for operation at 1.5V
- Offers 30% speed improvement over LVC at 1.8V.
- ± 24mA Output Drive at 3.3V
- CMOS low power consumption
- IOFF Supports Partial-Power-Down Mode Operation
- Inputs accept up to 5.5V
- ESD Protection Tested per JESD 22
   Exceeds 200-V Machine Model (A115-A)
   Exceeds 2000-V Human Body Model (A114-A)
- Latch-Up Exceeds 100mA per JESD 78, Class II
- Range of Package Options
- Direct Interface with TTL Levels
- SOT25, SOT353, and DFN1410: Assembled with "Green" Molding Compound (no Br, Sb)
- Lead Free Finish/ RoHS Compliant (Note 1)

#### **Pin Assignments**





#### **Applications**

- · Voltage Level Shifting
- · Bus Driver / Repeater
- · Power Down Signal Isolation
- General Purpose Logic
- · Wide array of products such as.
  - PCs, networking, notebooks, netbooks, PDAs
  - Computer peripherals, hard drives, CD/DVD ROM
  - o TV, DVD, DVR, set top box
  - o Cell Phones, Personal Navigation / GPS
  - o MP3 players ,Cameras, Video Recorders

Notes: 1. EU Directive 2002/95/EC (RoHS). All applicable RoHS exemptions applied. Please visit our website at http://www.diodes.com/products/lead\_free.html.

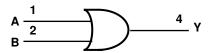
2. Pin 2 and pin 5 of the DFN1410 package are internally connected.



## **Pin Descriptions**

Pin Name	Description			
Α	Data Input			
В	Data Input			
GND	Ground			
Y	Data Output			
Vcc	Supply Voltage			

# Logic Diagram



## **Function Table**

Inp	Output	
Α	В	Υ
Н	Χ	Н
Χ	Н	Н
L	L	L



### **Absolute Maximum Ratings (Note 3)**

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD MM	Machine Model ESD Protection	200	V
V <sub>CC</sub>	Supply Voltage Range	-0.5 to 6.5	V
Vı	Input Voltage Range	-0.5 to 6.5	V
Vo	Voltage applied to output in high impedance or I <sub>OFF</sub> state	-0.5 to 6.5	V
V <sub>o</sub>	Voltage applied to output in high or low state	-0.3 to V <sub>CC</sub> +0.5	V
I <sub>IK</sub>	Input Clamp Current V <sub>I</sub> <0	-50	mA
I <sub>ok</sub>	Output Clamp Current	-50	mA
Io	Continuous output current	±50	mA
	Continuous current through Vdd or GND	±100	mA
T <sub>J</sub>	Operating Junction Temperature	-40 to 150	°C
T <sub>STG</sub>	Storage Temperature	-65 to 150	°C

Note: 3. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.



## **Recommended Operating Conditions (Note 4)**

Symbol		Parameter	Min	Max	Unit	
W	On avating Valtage	Operating	1.4	5.5	V	
V <sub>CC</sub>	Operating Voltage	Data retention only	1.2		V	
		V <sub>CC</sub> = 1.4 V to 1.95 V	0.65 X V <sub>CC</sub>			
V	LP-l- ll l l V-ll	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.7		V	
$V_{IH}$	High-level Input Voltage	V <sub>CC</sub> = 3 V to 3.6 V	2		V	
		V <sub>CC</sub> = 4.5 V to 5.5 V	0.7 X V <sub>CC</sub>			
		V <sub>CC</sub> = 1.4 V to 1.95 V		0.35 X V <sub>CC</sub>		
W	Low lovel input voltage	V <sub>CC</sub> = 2.3 V to 2.7 V		0.7	٧	
$V_{IL}$	Low-level input voltage	V <sub>CC</sub> = 3 V to 3.6 V		0.8	V	
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$		0.3 X V <sub>CC</sub>		
Vı	Input Voltage		0	5.5	V	
Vo	Output Voltage		0	V <sub>CC</sub>	V	
		Vcc=1.4 V		-3		
	High-level output current	V <sub>CC</sub> = 1.65 V		-4		
1		$V_{CC} = 2.3 \text{ V}$		-8		
I <sub>OH</sub>		V 2.V		-16	mA	
		$V_{CC} = 3 V$		-24		
		$V_{CC} = 4.5 \text{ V}$		-32		
		Vcc=1.4 V		3		
ı		V <sub>CC</sub> = 1.65 V		4		
		V <sub>CC</sub> = 2.3 V		8	mΑ	
I <sub>OL</sub>	Low-level output current			16		
		$V_{CC} = 3 V$		24		
		V <sub>CC</sub> = 4.5 V		32		
		V <sub>CC</sub> = 1.4 to 3V		20		
Δt/ΔV	Input transition rise or fall	V <sub>CC</sub> = 3.3 V ± 0.3 V		10	ns/V	
	rate	V <sub>CC</sub> = 5 V ± 0.5 V		5		
T <sub>A</sub>	Operating free-air temperature		-40	85	ōC	

Note: 4. Unused inputs should be held at Vcc or Ground.



## Electrical Characteristics (All typical values are at Vcc = 3.3V, T<sub>A</sub> = 25°C)

Over recommended free-air temperature range (unless otherwise noted)

Symbol	Parameter	<b>Test Conditions</b>	Vcc	Min	Тур.	Max	Unit	
		$I_{OH} = -100 \mu A$	1.4 V to 5.5V	V <sub>CC</sub> - 0.1				
		$I_{OH} = -3mA$	1.4 V	1.05			1	
		$I_{OH} = -4mA$	1.65 V	1.2			1	
$V_{OH}$	High Level Output Voltage	$I_{OH} = -8mA$	2.3V	1.9			V	
	Voltage	I <sub>OH</sub> = -16mA	3 V	2.4			1	
		$I_{OH} = -24mA$	3 V	2.3				
		I <sub>OH</sub> = -32mA	4.5 V	3.8				
		$I_{OL} = 100 \mu A$	1.4 V to 5.5V			0.1		
		$I_{OL} = 3mA$	1.4 V			.4		
		$I_{OL} = 4mA$	1.65 V			0.45	1	
V <sub>OL</sub>	High-level Input Voltage	I <sub>OL</sub> = 8mA	2.3V			0.3	V	
		I <sub>OL</sub> = 16mA	3 V			0.4		
		$I_{OL} = 24mA$	3 V			0.55		
		$I_{OL} = 32mA$	4.5			0.55		
I <sub>I</sub>	Input Current	$V_I = 5.5 \text{ V or GND}$	0 to 5.5 V			± 5	μA	
I <sub>OFF</sub>	Power Down Leakage Current	$V_1$ or $V_0 = 5.5V$	0			± 10	μA	
I <sub>CC</sub>	Supply Current	$V_1 = 5.5V$ of GND $I_0=0$	1.4 V to 5.5V			10	μA	
$\Delta I_{CC}$	Additional Supply Current	One input at V <sub>CC</sub> – 0.6 V Other inputs at V <sub>CC</sub> or GND	3 V to 5.5V			500	μA	
Ci	Input Capacitance	$V_i = V_{CC} - \text{ or GND}$	3.3		3.5		pF	
		SOT25	(Note 5)		204			
$\theta_{JA}$	Thermal Resistance Junction-to-Ambient	SOT353	(Note 5)		371		°C/W	
	Junction-to-Ambient	DFN1410	(Note 5)		430		1	
		SOT25	(Note 5)		52			
$\theta_{JC}$	Thermal Resistance	SOT353	(Note 5)		143		°C/W	
•	Junction-to-Case	DFN1410	(Note 5)		190			
			1 '	1			1	

Note: 5. Test condition for SOT25, SOT353, and DFN1410: Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.



### **Switching Characteristics**

Over recommended free-air temperature range, CL = 15pF (see Figure 1)

Parameter	From	то	Vcc = 1.5 V ± 0.1V			: 1.8 V .15V		: 2.5 V ).2V		3.3 V 3.3V	Vcc ±0	= 5 V ).5V	Unit
	(Input)	(OUTPUT)	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	
t <sub>pd</sub>	A or B	Y	1.9	7.2	1.3	5	0.6	3.5	0.7	2.9	0.7	2.9	ns

Over recommended free-air temperature range, CL = 30 or 50pF as noted (see Figure 2)

Parameter	From	то	Vcc = ± 0			: 1.8 V .15V		: 2.5 V ).2V		3.3 V 3.3V	Vcc :	= 5 V ).5V	Unit
	(Input)	(OUTPUT)	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	
t <sub>pd</sub>	A or B	Y	2.8	8	1.9	5.6	0.9	4.4	0.9	3.6	0.9	3.6	ns

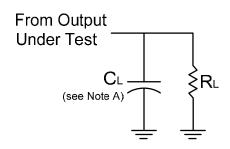
### **Operating Characteristics**

 $T_A = 25 \, {}^{\circ}C$ 

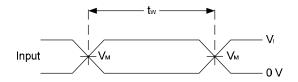
P	arameter	Test Conditions	Vcc = 1.5 V	Vcc = 1.8 V	Vcc = 2.5 V	Vcc = 3.3 V	Vcc = 5 V	Unit
$C_{pd}$	Power dissipation capacitance	f = 10 MHz	20	20	20	21	22	pF



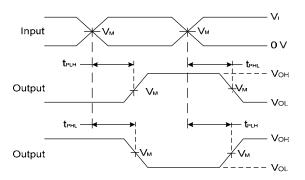
#### **Parameter Measurement Information**



Vcc	Inputs		V	C.	RL
VCC	Vı	t <sub>r</sub> /t <sub>f</sub>	V <sub>M</sub>	CL	ПL
1.5V±0.1V	V <sub>CC</sub>	≤2ns	V <sub>CC</sub> /2	15pF	1ΜΩ
1.8V±0.15V	V <sub>CC</sub>	≤2ns	V <sub>CC</sub> /2	15pF	1ΜΩ
2.5V±0.2V	V <sub>CC</sub>	≤2ns	V <sub>CC</sub> /2	15pF	1ΜΩ
3.3V±0.3V	3V	≤2.5ns	1.5V	15pF	1ΜΩ
5V±0.5V	$V_{CC}$	≤2.5ns	V <sub>CC</sub> /2	15pF	1ΜΩ



**Voltage Waveform Pulse Duration** 



**Voltage Waveform** Propagation Delay Times
Inverting and Non Inverting Outputs

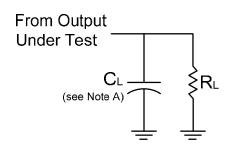
Notes: A. Includes test lead and test apparatus capacitance.

- B. All pulses are supplied at pulse repetition rate ≤ 10 MHz.
  C. Inputs are measured separately one transition per measurement.
- D. t<sub>PLH</sub> and t<sub>PHL</sub> are the same as t<sub>PD.</sub>

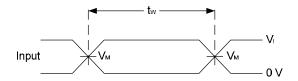
Figure 1. Load Circuit and Voltage Waveforms



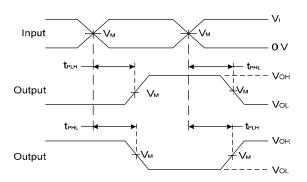
#### **Parameter Measurement Information (Continued)**



Vcc	Inp	outs	V <sub>M</sub>	CL	RL
	V <sub>I</sub>	t <sub>r</sub> /t <sub>f</sub>	- 101	o <sub>L</sub>	
1.5V±0.1V	V <sub>CC</sub>	≤2ns	V <sub>CC</sub> /2	30pF	1ΚΩ
1.8V±0.15V	V <sub>CC</sub>	≤2ns	V <sub>CC</sub> /2	30pF	1ΚΩ
2.5V±0.2V	V <sub>CC</sub>	≤2ns	V <sub>CC</sub> /2	30pF	500Ω
3.3V±0.3V	3V	≤2.5ns	1.5V	50pF	500Ω
5V±0.5V	V <sub>CC</sub>	≤2.5ns	V <sub>CC</sub> /2	50pF	500Ω



Voltage Waveform Pulse Duration



Voltage Waveform
Propagation Delay Times
Inverting and Non Inverting Outputs

Notes: A. Includes test lead and test apparatus capacitance.

B. All pulses are supplied at pulse repetition rate ≤ 10 MHz.

C. Inputs are measured separately one transition per measurement.

D. t<sub>PLH</sub> and t<sub>PHL</sub> are the same as t<sub>PD.</sub>

Figure 2. Load Circuit and Voltage Waveforms



### **Ordering Information**

T4LVCE1G 32 XXX - 7

Logic Device Function Package Packing

74: Logic Prefix 32: 2-Input W5: SOT25 7: Tape & Reel

LVCE: 1.4 to 5.5V OR-Gate SE: SOT353

FZ4: DFN1410

Family

1G: One gate

	Device	Package Packaging		7" Tape and Reel		
	Device	Code	(Note 5)	Quantity	Part Number Suffix	
<b>Pb</b> ,	74LVCE1G32W5-7	W6	SOT25	3000/Tape & Reel	-7	
<b>Pb</b> ,	74LVCE1G32SE-7	SE	SOT353	3000/Tape & Reel	-7	
<b>Pb</b> ,	74LVCE1G32FZ4-7	FZ4	DFN1410	5000/Tape & Reel	-7	

Note: 6. Pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.



### **Marking Information**

#### (1) SOT25 and SOT353

#### (Top View)

5 XX Y W X

2

1

XX: Identification code

Y: Year 0~9

 $\underline{W}$ : Week : A $^{\sim}$ Z : 1 $^{\sim}$ 26 week;

a~z: 27~52 week; z represents 52 and 53 week

X: A~Z: Internal code

Part Number	Package	Identification Code
74LVCE1G32W5	SOT25	PW
74LVCE1G32SE	SOT353	PW

#### (2) DFN1410

#### (Top View)

3

<u>XX</u>  $\underline{Y} \underline{W} \underline{X}$  XX: Identification Code

<u>Y</u> : Year : 0~9

 $\overline{W}$ : Week : A~Z : 1~26 week;

a~z: 27~52 week; z represents

52 and 53 week

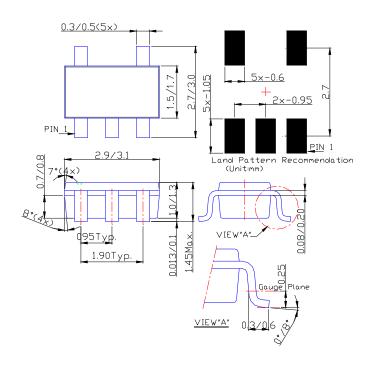
 $X : A \sim Z : Internal code$ 

Part Number	Package	Identification Code
74LVCE1G32FZ4	DFN1410	PW

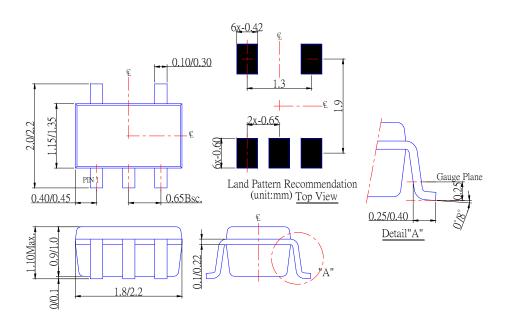


### Package Outline Dimensions (All Dimensions in mm)

#### (1) Package Type: SOT25



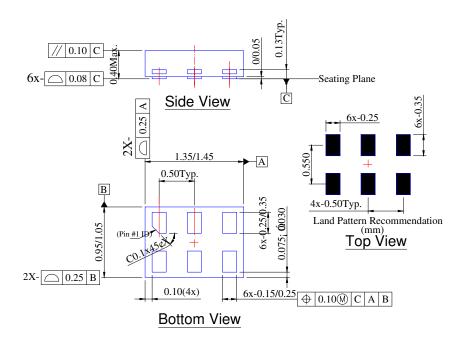
#### (2) Package Type: SOT353





### Package Outline Dimensions (All Dimensions in mm)

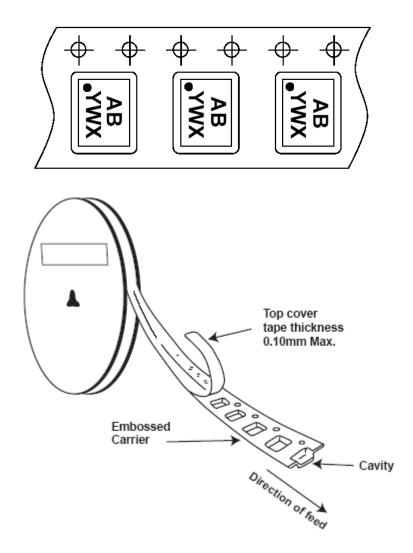
#### (3) Package Type: DFN1410





### **Taping Orientation (Note 7)**

#### For DFN1410



Note: 7. The taping orientation of the other package type can be found on our website at http://www.diodes.com/datasheets/ap02007.pdf



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